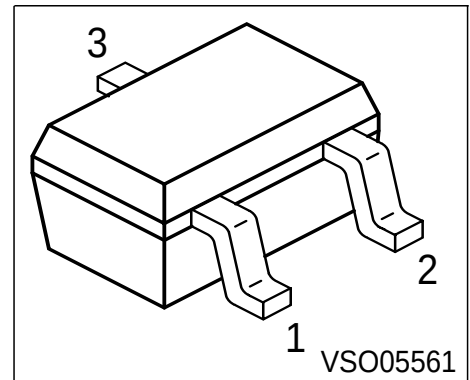
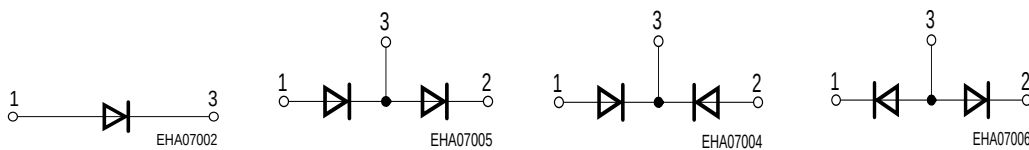


Silicon Schottky Diodes

- For mixer applications in the VHF / UHF range
- For high-speed switching applications


BAT68W
BAT68-04W
BAT68-05W
BAT68-06W


ESD: Electrostatic discharge sensitive device, observe handling precaution!

Type	Marking	Pin Configuration			Package
BAT68W	84s	1 = A1	2 = C2	3 = C1/A2	SOT323
BAT68-04W	85s	1 = A1	2 = A2	3 = C1/2	SOT323
BAT68-05W	86s	1 = C1	2 = C2	3 = A1/2	SOT323
BAT68-06W	83s	1 = A1	2 n.c.	3 = C	SOT323

Maximum Ratings

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_R	8	V
Forward current	I_F	130	mA
Total power dissipation BAT68W, $T_S = 97\text{ °C}$	P_{tot}	150	mW
BAT68-04W...06W, $T_S = 92\text{ °C}$	P_{tot}	150	
Junction temperature	T_j	150	°C
Operating temperature range	T_{op}	-65 ... 150	
Storage temperature	T_{stg}	-65 ... 150	

Thermal Resistance

Junction - soldering point ¹⁾	R_{thJS}		K/W
BAT68W		≤ 355	
BAT68-04W...06W		≤ 390	

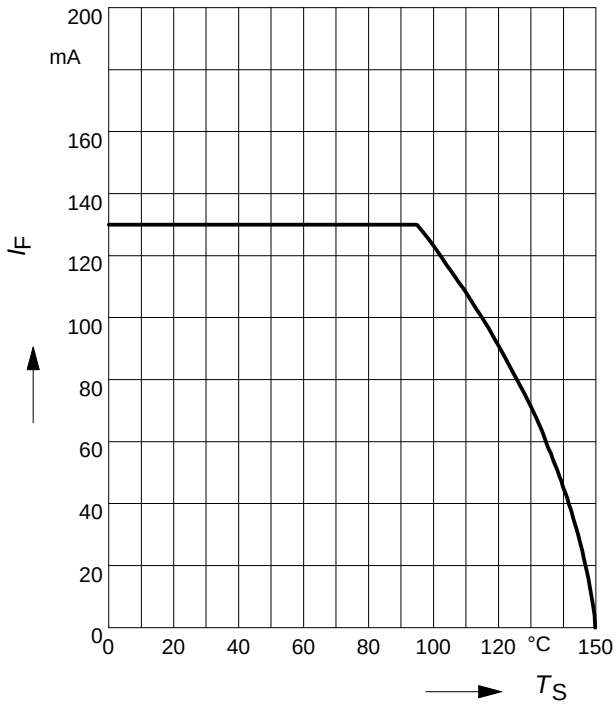
¹⁾For calculation of R_{thJA} please refer to Application Note Thermal Resistance

Electrical Characteristics at $T_A = 25\text{ °C}$, unless otherwise specified.

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC characteristics					
Breakdown voltage $I_{(BR)} = 10\text{ }\mu\text{A}$	$V_{(BR)}$	8	-	-	V
Reverse current $V_R = 1\text{ V}$	I_R	-	-	0.1	μA
Reverse current $V_R = 1\text{ V}, T_A = 60\text{ }^{\circ}\text{C}$	I_R	-	-	1.2	
Forward voltage $I_F = 1\text{ mA}$ $I_F = 10\text{ mA}$	V_F	- 340	318 390	340 500	mV
AC characteristics					
Diode capacitance $V_R = 0\text{ V}, f = 1\text{ MHz}$	C_T	-	-	1	pF
Differential forward resistance $I_F = 5\text{ mA}, f = 10\text{ kHz}$	R_f	-	-	10	Ω

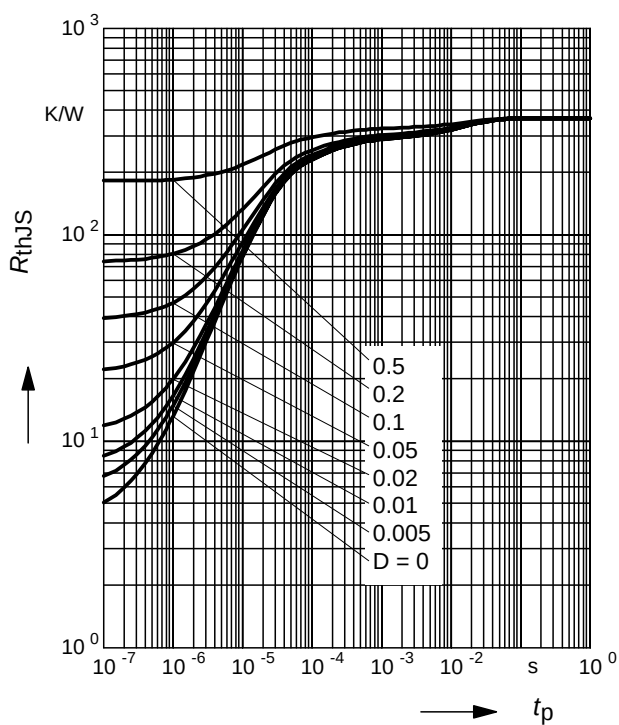
Forward current $I_F = f(T_S)$

BAT68W



Permissible Pulse Load $R_{thJS} = f(t_p)$

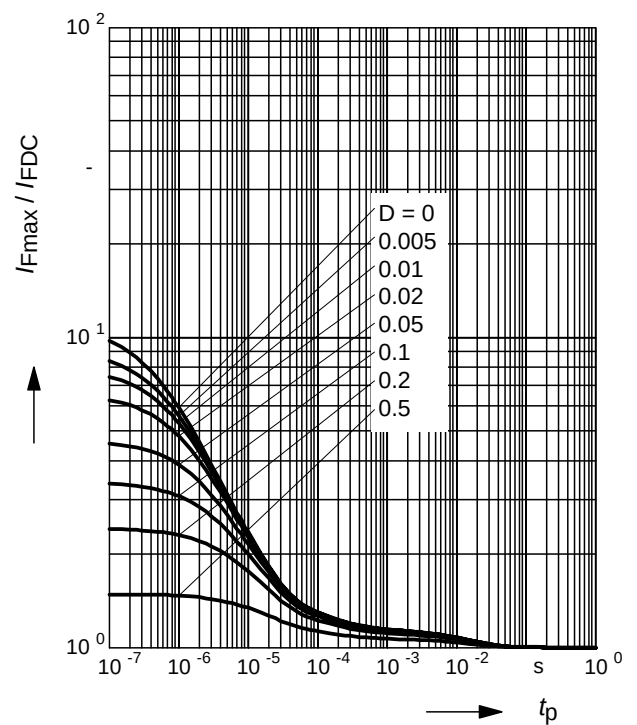
BAT68W



Permissible Pulse Load

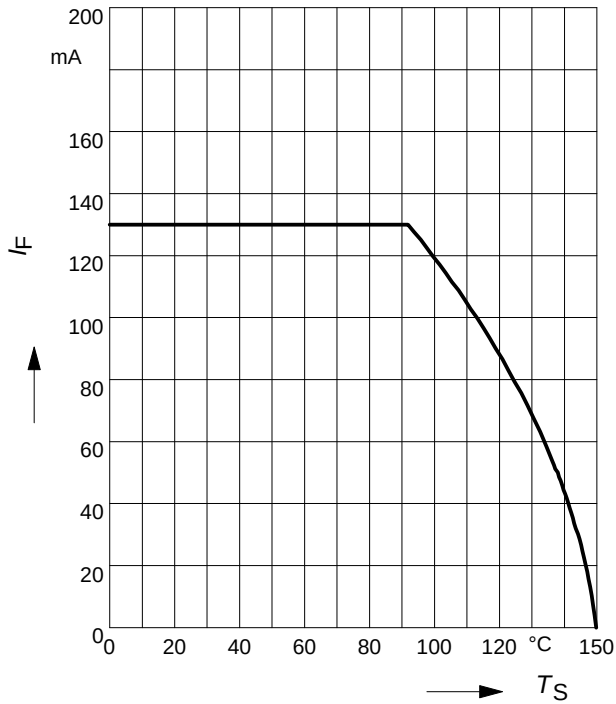
$$I_{Fmax} / I_{FDC} = f(t_p)$$

BAT68W



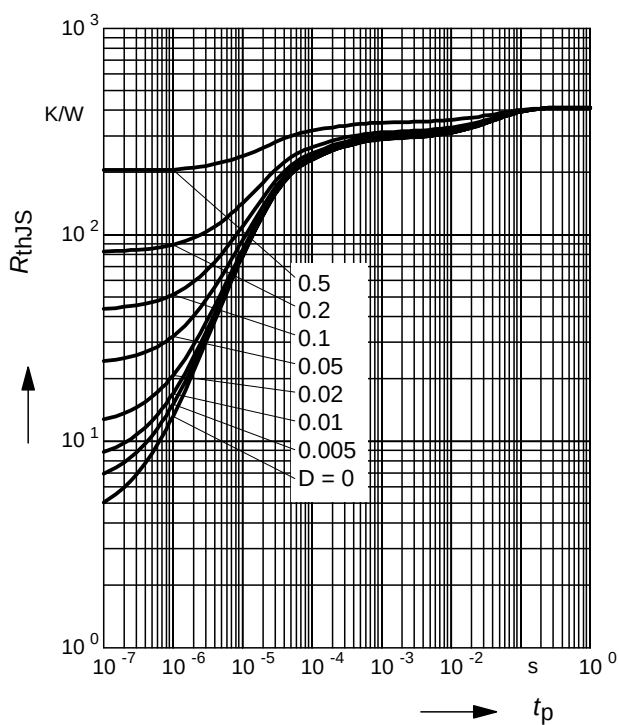
Forward current $I_F = f(T_S)$

BAT68-04W...06W



Permissible Pulse Load $R_{thJS} = f(t_p)$

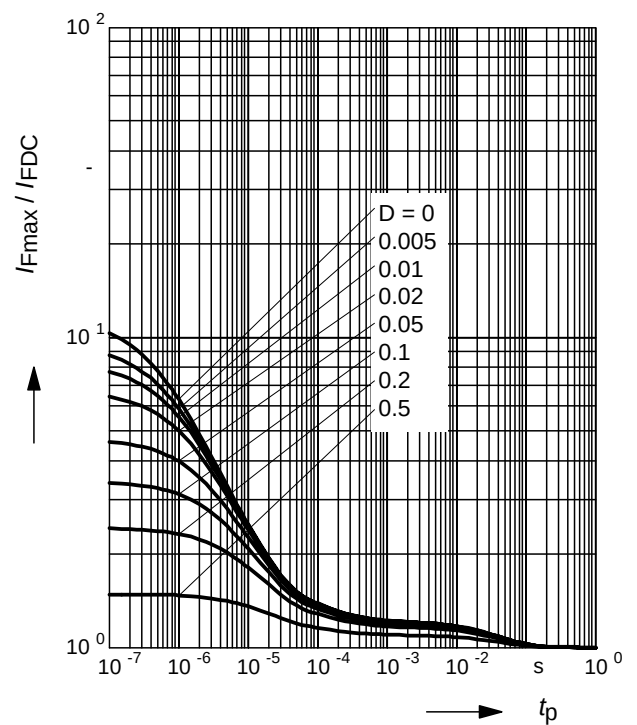
BAT68-04W...06W



Permissible Pulse Load

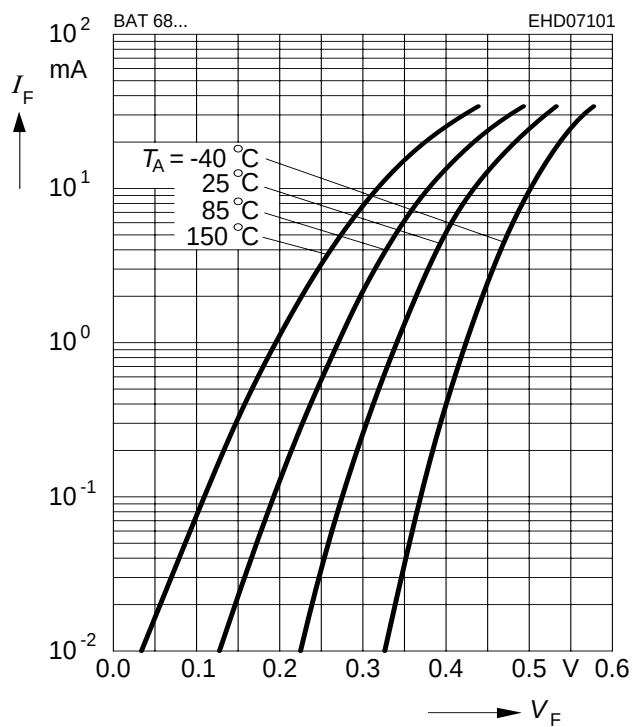
$$I_{Fmax} / I_{FDC} = f(t_p)$$

BA 68-04W...06W



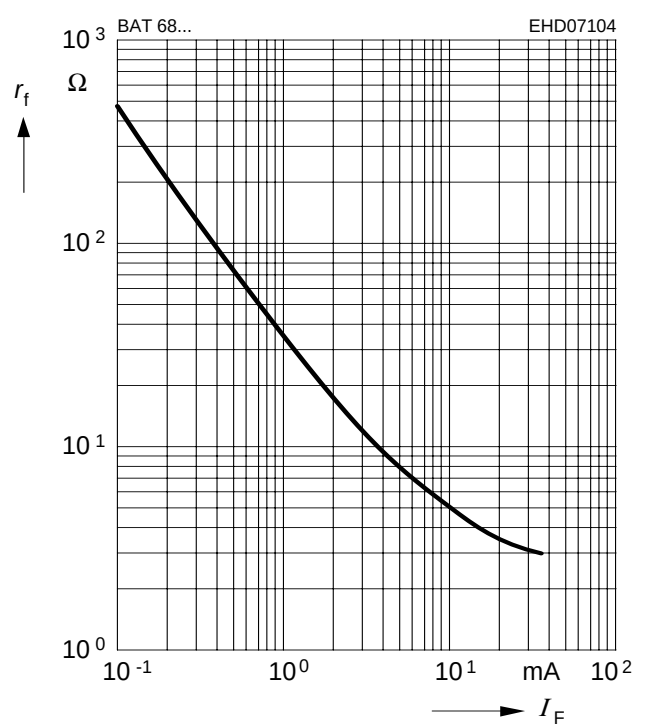
Forward current $I_F = f(V_F)$

$T_A = \text{Parameter}$



Differential forward resistance $r_f = f(I_F)$

$f = 10 \text{ kHz}$



Diode capacitance $C_T = f(V_R)$

$f = 1 \text{ MHz}$

